

TDS:EMIC

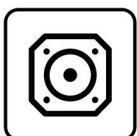
拓電半導體

自主封測 品質把控 售後保障

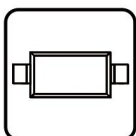
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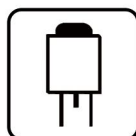
電源管理



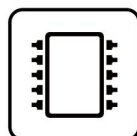
顯示驅動



二三極管



LDO穩壓器



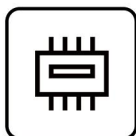
觸摸芯片



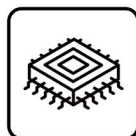
MOS管



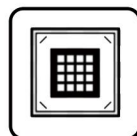
運算放大器



存儲芯片



MCU



串口通信

LM7805-TD

產品規格說明書

TO-220-3L Plastic-Encapsulate Voltage Regulators

Three-terminal positive voltage regulator

FEATURES

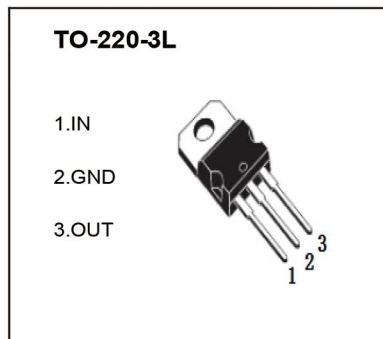
Maximum Output current I_{OM} : 1.5 A

Output voltage V_o : 5V

Continuous total dissipation

P_D : 1.5 W ($T_a = 25^\circ\text{C}$)

15 W ($T_c = 25^\circ\text{C}$)



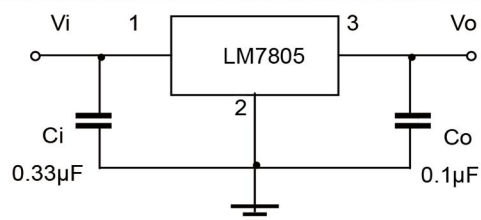
ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

Parameter	Symbol	Value	Unit
Input Voltage	V_i	35	V
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	83.3	$^\circ\text{C/W}$
Thermal Resistance from Junction to Case	$R_{\theta JC}$	8.3	$^\circ\text{C/W}$
Operating Junction Temperature Range	T_{OPR}	0~+150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55~+150	$^\circ\text{C}$

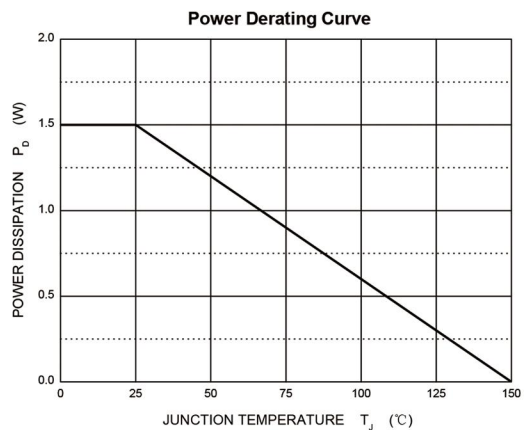
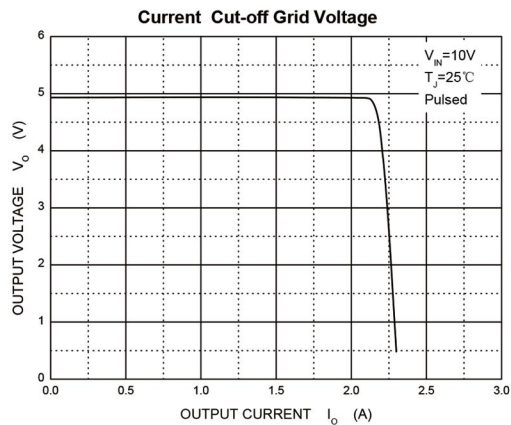
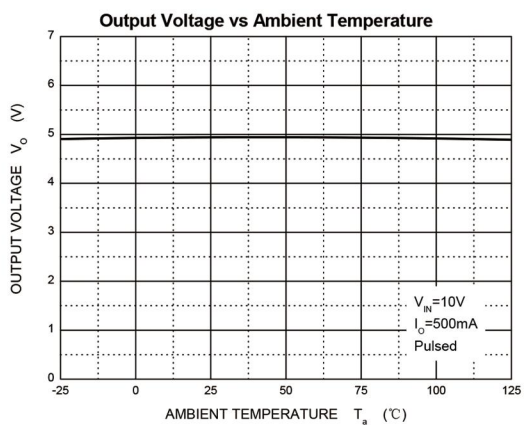
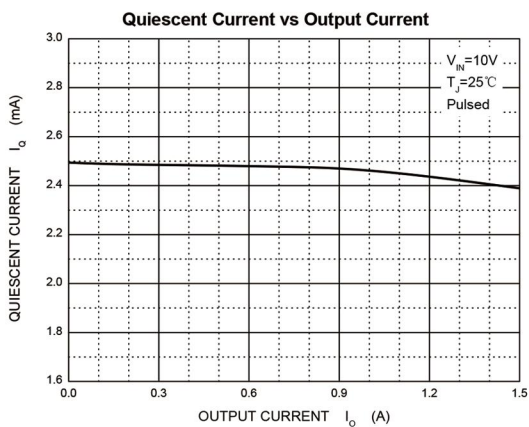
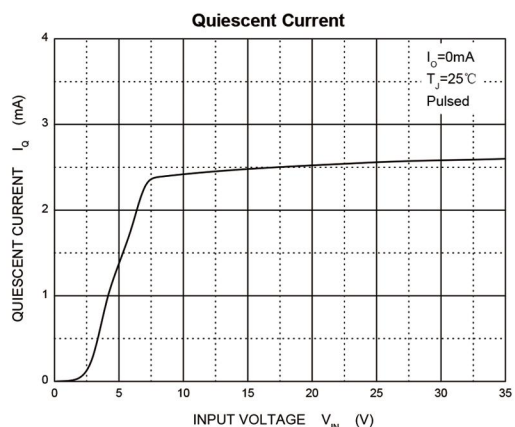
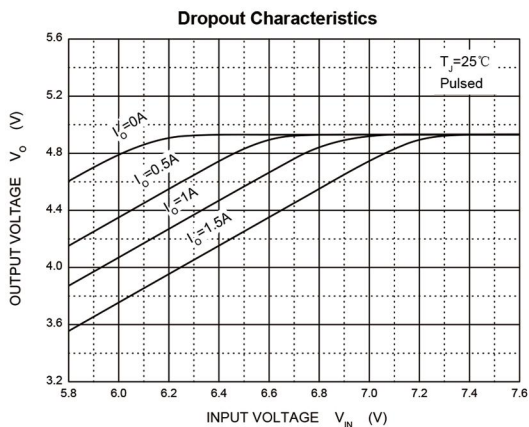
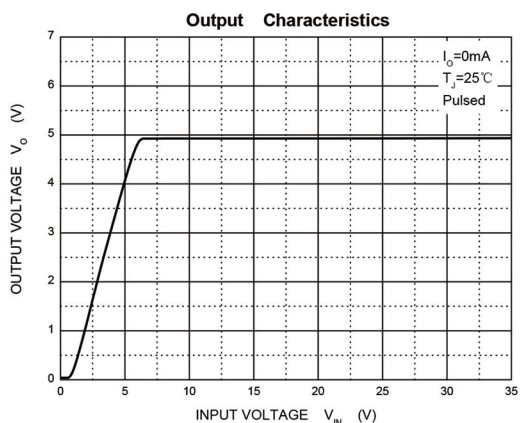
ELECTRICAL CHARACTERISTICS AT SPECIFIED VIRTUAL JUNCTION TEMPERATURE ($V_i=10\text{V}$, $I_o=500\text{mA}$, $C_i=0.33\mu\text{F}$, $C_o=0.1\mu\text{F}$, unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Output voltage	V_o	25°C	4.8	5.0	5.2	V
		$7\text{V} \leq V_i \leq 20\text{V}$, $I_o=5\text{mA}-1\text{A}$, $P \leq 15\text{W}$	4.75	5.00	5.25	V
Load Regulation	ΔV_o	$I_o=5\text{mA}-1.5\text{A}$, 25°C		9	100	mV
		$I_o=250\text{mA}-750\text{mA}$, 25°C		4	50	mV
Line regulation	ΔV_o	$7\text{V} \leq V_i \leq 25\text{V}$, 25°C		4	100	mV
		$8\text{V} \leq V_i \leq 12\text{V}$, 25°C		1.6	50	mV
Quiescent Current	I_q	25°C		5	8	mA
Quiescent Current Change	ΔI_q	$7\text{V} \leq V_i \leq 25\text{V}$, $0-125^\circ\text{C}$		0.3	1.3	mA
		$5\text{mA} \leq I_o \leq 1\text{A}$, $0-125^\circ\text{C}$		0.03	0.5	mA
Output Noise Voltage	V_N	$10\text{Hz} \leq f \leq 100\text{KHz}$, 25°C		42		μV
Output voltage drift	$\Delta V_o / \Delta T$	$I_o=5\text{mA}$, $0-125^\circ\text{C}$		-1.1		$\text{mV}/^\circ\text{C}$
Ripple Rejection	RR	$8\text{V} \leq V_i \leq 18\text{V}$, $f=120\text{Hz}$, $0-125^\circ\text{C}$	62	73		dB
Dropout Voltage	V_d	$I_o=1\text{A}$, 25°C		2		V
Output resistance	R_o	$f=1\text{KHz}$, 25°C		10		$\text{m}\Omega$
Short Circuit Current	I_{sc}	25°C		230		mA
Peak Current	I_{pk}	25°C		2		A

TYPICAL APPLICATION



D, Oct, 2014



D, Oct, 2014